

# <C band Internally Matched Power GaAs FET>

# **MGFC47B3538B**

3.5 - 3.8GHz BAND / 50W

### DESCRIPTION

The MGFC47B3538B is an internally impedance-matched GaAs power FET especially designed for use in 3.5 - 3.8 GHz band amplifiers. The hermetically sealed metal-ceramic package guarantees high reliability.

### **FEATURES**

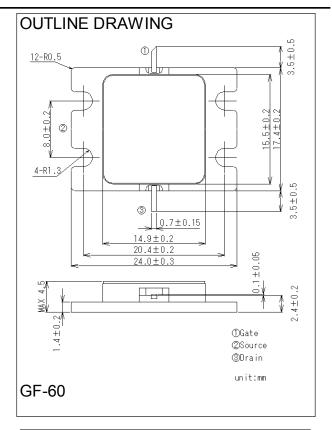
Crass AB operation

Internally matched to 50(ohm)

- High output power: Po(SAT) = 50 W (typ.)
- High power gain: GP = 10 dB (TPE.) @Po = 37dBm
- Distortion: EVM = 2.0% (TPE.) @ Po = 37dBm

### **Recommended Bias Condition**

- Vd = 12(V)
- ID = 1.5 (A)
- Rg = 10 ohm



#### Keep Safety first in your circuit designs!

Mitsubishi Electric Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them.

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### ABSOLUTE MAXIMUM RATINGS

ELECTRICAL CARACTERISTICS

(Ta	=250	leg	.C

Symbol	Parameter	Ratings	Unit		
VGDO	Gate to drain voltage	-15	V		
VGSO	Gate to source voltage	-10	V		
MAXID	Maximum drain current	12	А		
PT *1	Total power dissipation	115	W		
Tch	Channel temperature	175	deg.C		
Tstg	Storage temperature	-55 / +150	deg.C		
*1 : Tc=25deg.C					

#### (Ta=25deg.C)

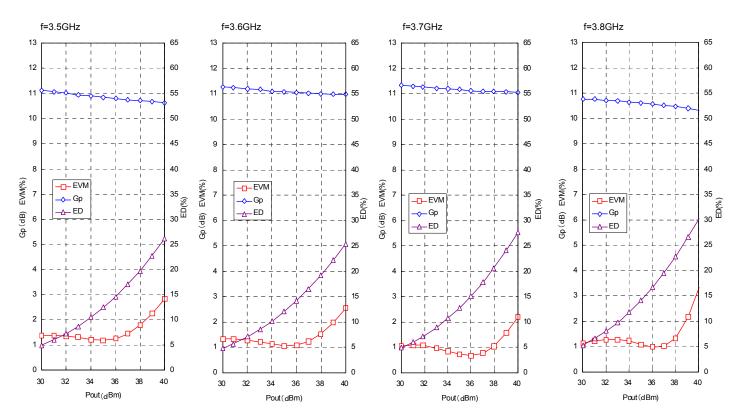
Symbol	Parameter	Test conditions	Limits		Unit	
			Min.	Тур.	Max.	
VGS(off)	Gate to source cut-off voltage	VDS = 3V , ID = 100mA	-0.5	-	-3.0	V
Po(SAT)	Output power	VDS=12V, ID(RF off)=1.5A, f=3.5-3.8GHz	-	47	-	dBm
GP	Power gain		9.0	10.5	-	dB
ID	Drain current	VDS=12V, ID(RF off)=1.5A, f=3.5-3.8GHz	-	2.0	3	Α
EVM *2	Error Vector Magnitude	Pout=37dBm	-	1.5	2.5	%
Rth(ch-c) *3	Thermal resistance	delta Vf method	-	0.65	1.2	deg.C/W

\*2 :WiMAX Downlink, 64QAM-3/4, Channel Bandwidth: 7MHz

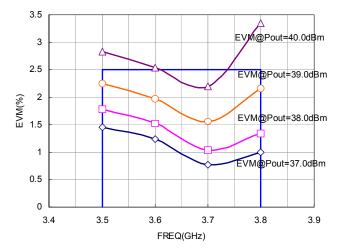
\*3 : Channel-case

### <C band internally matched power GaAs FET> MGFC42V7177 7.1 - 7.7GHz BAND / 16W

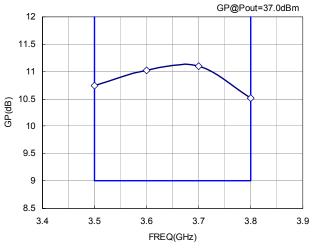
### EVM(@WiMAX) vs . Pout characteristics of MGFC47B3538B-01



EVM(@WiMax) vs. FREQ characteristics of MGFC47B3538B-01

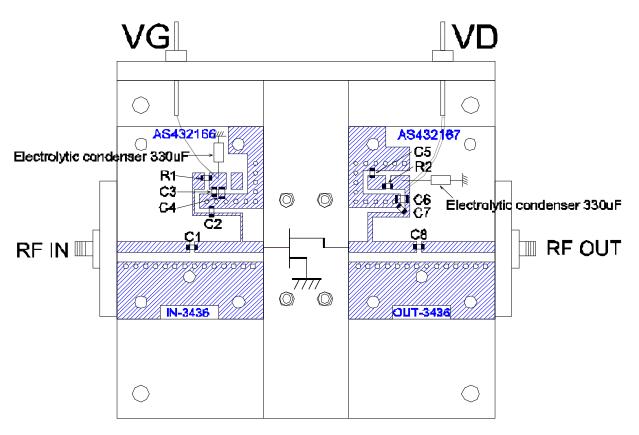


oGP(@WiMax) vs. FREQ characteristics of MGFC47B3538B-01



<C band internally matched power GaAs FET> MGFC42V7177 7.1 - 7.7GHz BAND / 16W

# MGFC47B3538B RF TEST FIXTURE



C1,C2,C7,C8=GR708 8pF C3,C5=1000pF C4=100nF C6=470nF R1= 100hm R2=CR10 510hm Board material:Teflon t=0.8mm Specific dielectric constant=2.6 UNIT:(mm)

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